















ESD

TVS

MOS

LDO

Diode

Sensor

DC-DC

Product Specification

Domestic Part Number	CEM9926A
Overseas Part Number	CEM9926A
▶ Equivalent Part Number	CEM9926A





Features

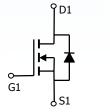
$$V_{DS}(V) = 20V$$

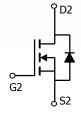
 $I_D = 7A$

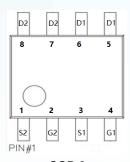
 $R_{DS(ON)}$ < 26m Ω (V_{GS} = 4.5V)

 $R_{DS(ON)} < 33 m\Omega (V_{GS} = 2.5V)$

 $R_{DS(ON)}$ < 42m Ω (V_{GS} = 1.8V)







SOP-8

Absolute Maximum Ratings T_A=25°C unless otherwise noted

Parameter		Symbol	Maximum	Units
Drain-Source Voltage	;	V_{DS}	20	V
Gate-Source Voltage		V_{GS}	±8	V
Continuous Drain	T _A =25°C		7	
Current ^A	T _A =70°C	I_D	6	Α
Pulsed Drain Current B		I _{DM}	40	
	T _A =25°C	P_{D}	2	W
Power Dissipation	T _A =70°C		1.44	VV
Junction and Storage Temperature Range		T_J , T_{STG}	-55 to 150	°C

Thermal Characteristics

Parameter		Symbol	Тур	Max	Units
Maximum Junction-to-Ambient A	t ≤ 10s	$R_{\theta JA}$	48	62.5	°C/W
Maximum Junction-to-Ambient A	Steady-State	I V ⊕JA	74	110	°C/W
Maximum Junction-to-Lead ^C	Steady-State	$R_{ heta JL}$	35	40	°C/W



Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
STATIC F	PARAMETERS	-	<u> </u>		-		
BV _{DSS}	Drain-Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$		20			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =16V, V _{GS} =0V				1	
DSS	Zero Gate Voltage Drain Current		T _J =55°C			5	μΑ
I_{GSS}	Gate-Body leakage current	V_{DS} =0V, V_{GS} =±8V				100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS} I_{D}=250\mu A$		0.3	0.5	0.8	V
$I_{D(ON)}$	On state drain current	V_{GS} =4.5V, V_{DS} =5V		30			Α
		V_{GS} =4.5V, I_D =7A			21.6	26	mO
R	Static Drain-Source On-Resistance		T _J =125°C		29.2	36	mΩ
R _{DS(ON)}	Static Drain-Source On-Resistance	V_{GS} =2.5V, I_D =5A			26.4	33	mΩ
		V_{GS} =1.8V, I_D =4A			33.3	42	mΩ
g _{FS}	Forward Transconductance	V_{DS} =5V, I_{D} =5A			22		S
V_{SD}	Diode Forward Voltage	I _S =1A			0.76	1	V
I_S	Maximum Body-Diode Continuous Curr	ent				3	Α
DYNAMIC	PARAMETERS						
C_{iss}	Input Capacitance				1050		pF
Coss	Output Capacitance	V _{GS} =0V, V _{DS} =10V, f=1MHz			163		pF
C_{rss}	Reverse Transfer Capacitance				129		pF
R_g	Gate resistance	V _{GS} =0V, V _{DS} =0V, f=1MHz			4		Ω
SWITCHI	NG PARAMETERS		•		•		
Q_g	Total Gate Charge				15.2		nC
Q_{gs}	Gate Source Charge	V_{GS} =4.5V, V_{DS} =10V, I_{D} =7A			1		nC
Q_{gd}	Gate Drain Charge				4		nC
t _{D(on)}	Turn-On DelayTime				6.5		ns
t _r	Turn-On Rise Time	V_{GS} =5V, V_{DS} =10V, R_L =1.5 Ω , R_{GEN} =3 Ω			9		ns
$t_{D(off)}$	Turn-Off DelayTime				56.5		ns
t _f	Turn-Off Fall Time				13.2		ns
t _{rr}	Body Diode Reverse Recovery time	I _F =5A, dI/dt=100A/μs	1		21		ns
Q_{rr}	Body Diode Reverse Recovery charge	I _F =5A, dI/dt=100A/μs			7.1		nC

A: The value of $R_{\theta,JA}$ is measured with the device mounted on 1in^2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The value in any a given application depends on the user's specific board design. The current rating is based on the t ≤ 10s thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C. The R $_{\theta JA}$ is the sum of the thermal impedence from junction to lead $R_{\theta JL}$ and lead to ambient.

D. The static characteristics in Figures 1 to 6 are obtained using $80\mu s$ pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The SOA curve provides a single pulse rating.



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

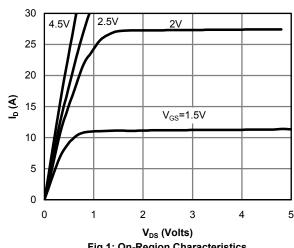


Fig 1: On-Region Characteristics

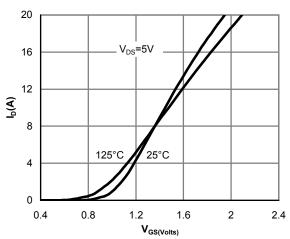


Figure 2: Transfer Characteristics

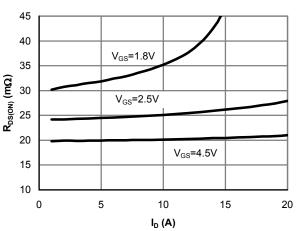


Figure 3: On-Resistance vs. Drain Current and **Gate Voltage**

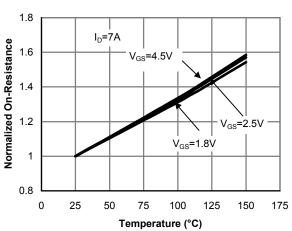


Figure 4: On-Resistance vs. Junction Temperature

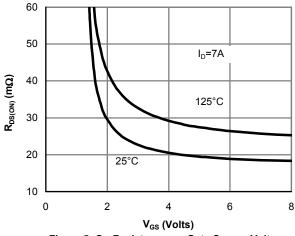


Figure 5: On-Resistance vs. Gate-Source Voltage

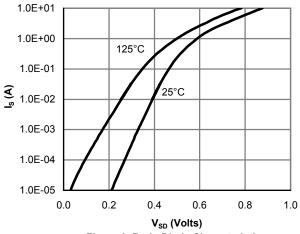


Figure 6: Body-Diode Characteristics



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

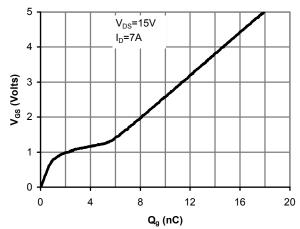


Figure 7: Gate-Charge Characteristics

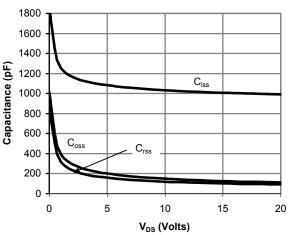


Figure 8: Capacitance Characteristics

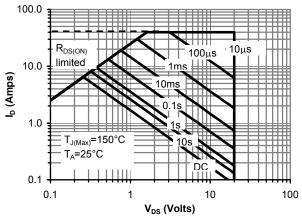


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

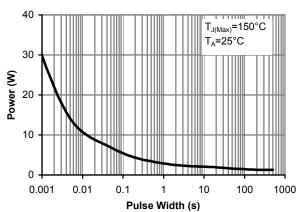


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note E)

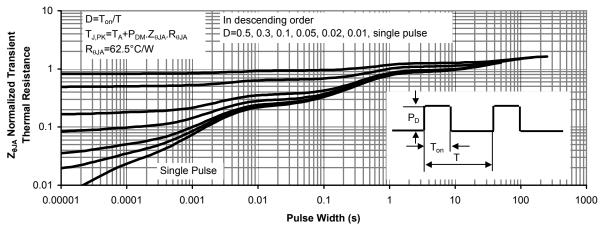
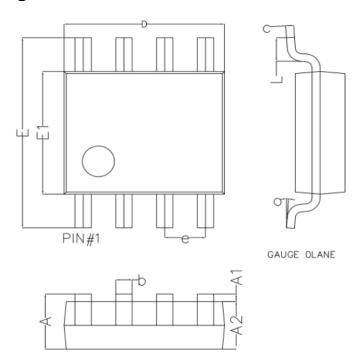


Figure 11: Normalized Maximum Transient Thermal Impedance

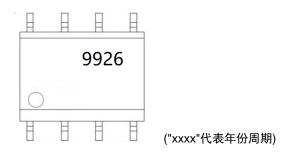


Package Mechanical Data-SOP-8



Symbol	Dim i			
Symbol	Min	Nor	Max	
A	1. 350	1.550	1.750	
A1	0.100	0. 175	0. 250	
A2	1.350	1.450	1.550	
b	0. 330	0. 420	0. 510	
С	0. 170	0. 210	0. 250	
D	4. 800	4. 900	5. 000	
е	1. 270 (BSC)			
Е	5. 800	6. 000	6. 200	
E1	3. 800	3. 900	4. 000	
L	0.400	0.835	1. 2700	
О	0°	4°	8°	

Marking



Ordering information

Order Code	Order Code Package		Deliverymode
CEM9926A	SOP-8	3000	Tape and reel



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